

Performance Constraints of All-Perovskite Tandem Solar Cells in Low-Intensity, Low-Temperature Environments

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All-perovskite tandem solar cells (2J-PSCs) reach the highest power-to-weight ratios, making them promising candidates for space applications. To determine their potential for future deep space missions, this study assesses the performance of 2J-PSCs under low-intensity and low-temperature (LILT) conditions, akin to those found near Saturn, the Asteroid belt, or in eclipse. Temperature-dependent current density-voltage (J - V) measurements under varying solar intensities (AM0, 0.1 AM0, 0.01 AM0) reveal that the 2J-PSCs, comprising 1.80 eV high-bandgap and 1.27 eV low-bandgap perovskites, exhibit significant efficiency losses at lower temperatures and low light levels. In contrast, 1.54 eV single-junction PSCs (1J-PSCs) exhibit resilient performance, maintaining or even increasing their power conversion efficiency at low temperatures. The main performance problem of the 2J-PSCs is then identified as a demixing of the 1.80 eV perovskite due to its high Br ratio at temperatures below 250 K. This demixing at low temperatures leads to a significant increase in ion-induced performance losses as well as current imbalances between the two subcells in the monolithic tandem. Together, this causes severe S-shapes in solar cell operation and impedes the operation of the monolithic interconnected tandem solar cells. Notably, these limitations vanish upon heating, leading to a recovery of performance.

launch costs to low-Earth orbit (LEO) currently remain at around \$2700 kg⁻¹.^[3] Solar cells have proven to be a reliable and cost-effective way of powering space-based infrastructure once it is in orbit. To date, III-V semiconductor-based triple- and quadruple-junction solar cells provide power-to-weight ratios of $\approx 1 \text{ W g}^{-1}$, however, high production costs due to slow epitaxy processes and the scarcity of raw elements are becoming increasingly significant issues.^[4] Lower-cost, thin-film solar cells could therefore be an important breakthrough for the new space economy. Perovskite solar cells (PSCs) with good optoelectronic properties, as well as broad tunability of their bandgap ranging from 1.27 to 2.3 eV, have recently achieved efficiencies of $> 26\%$ and $> 30\%$ in single-junction (1J) and tandem (2J) perovskite solar cells, respectively.^[5-8]

Their compatibility with flexible substrates, cost-effective production, and a high power-to-weight ratio of up to 29 W g^{-1} not only brought PSCs to the forefront in the terrestrial solar industry but also

propelled them forward as promising candidates for space applications.^[9-12] The space environment presents a unique set of extreme conditions that far exceed the demands encountered in terrestrial applications. Since the extraterrestrial solar spectrum (Air Mass 0, AM0) contains a considerably higher

1. Introduction

The last decade has witnessed the rapid expansion of the commercial space sector, incorporating space tourism, satellite services, and many more.^[1,2] Despite the drastic reduction over time,

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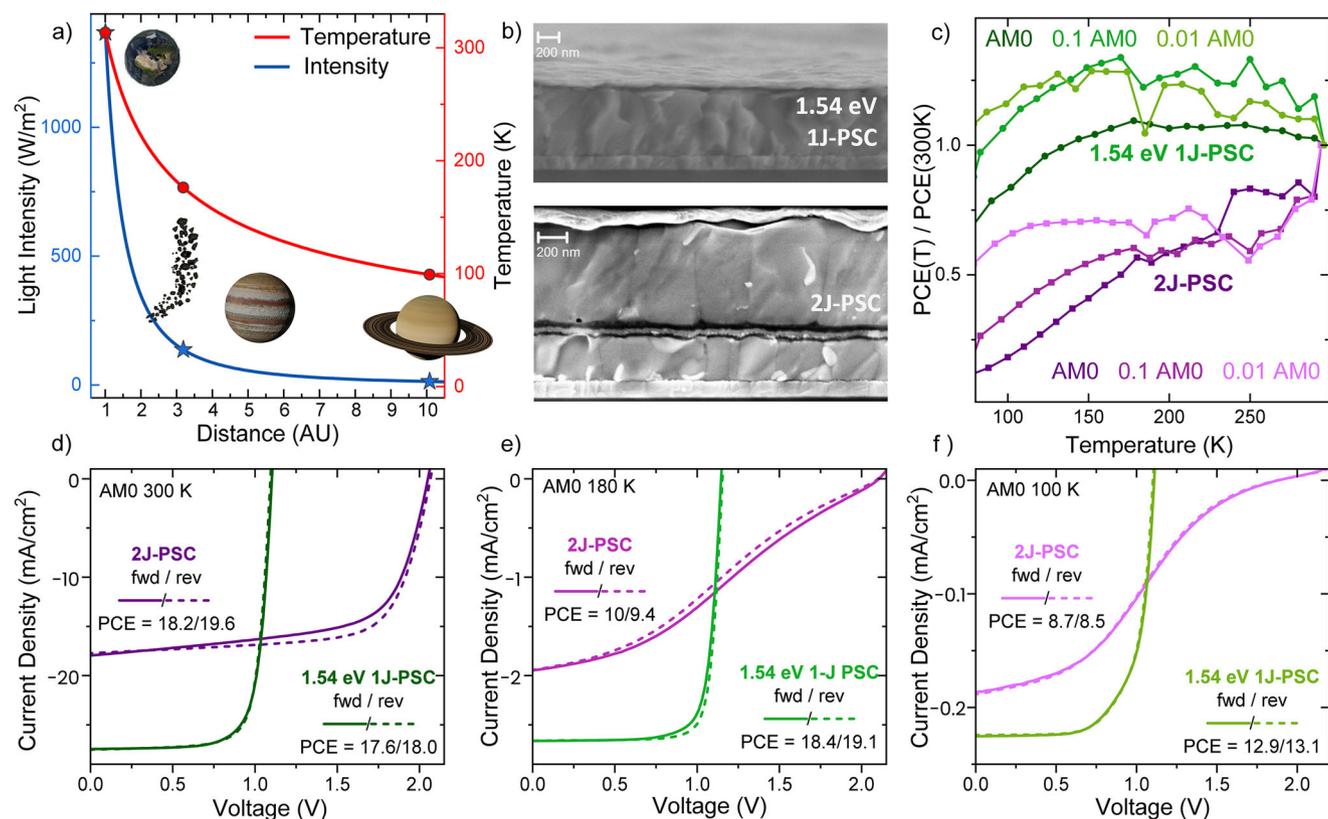


Figure 1. Performance and stability of perovskite solar cells (PSCs) under space-relevant conditions. a) Variation of light intensity (blue curve) and temperature (red curve) with distance from the Sun (AU), highlighting conditions at different planetary distances. b) Cross-sectional scanning electron microscopy (SEM) images of 1.54 eV single-junction (1J-PSC) and tandem (2J-PSC) perovskite solar cells, showing their layer structures. c) Normalized power conversion efficiency ($PCE(T)/PCE(300\text{ K})$) of the 1.54 eV 1J-PSC and 2J-PSC as a function of temperature under AM0, 0.1 AM0, and 0.01 AM0 light intensities. d–f) current density–voltage (J – V) curves (forward/reverse scan, 154 mV s^{-1}) of 1.54 eV 1J-PSCs and 2J-PSCs at various light intensities and temperatures: (d) AM0 at 300 K, (e) 0.1 AM0 at 180 K, (f) 0.01 AM0 at 100 K. Planet textures derived from publicly available NASA imagery (Courtesy NASA/JPL-Caltech). No endorsement by NASA is implied.

proportion of ultraviolet (UV) radiation in comparison to the terrestrial Air Mass 1.5 Global (AM1.5G) irradiation, resistance to UV degradation is crucial for space applications.^[13–17] Furthermore, atomic oxygen (ATOX), which is most prevalent in low-Earth orbit (LEO), is highly corrosive, leading to erosion and degradation.^[17,18] While these two threats can be tackled by barrier layers and encapsulation strategies, the harsh radiation environment cannot be easily shielded in low-weight solar cells. High-energy protons and electrons can displace ions and create defects that are known to diminish performance.^[19] Previously, we tested various perovskite-based single-junction and tandem solar cells for their resilience to harsh radiation and found that halide perovskites exhibit excellent tolerance combined with remarkable self-healing due to their soft lattice.^[20–27] This makes metal halide perovskites ideal candidates not only for terrestrial applications but also for space applications, potentially even for outer-space missions. Both temperature and light intensity vary significantly depending on the distance from the sun. For example, solar irradiance around the asteroid belt at a distance of 3 astronomical units (AU) is ≈ 10 times lower than in Earth's orbit (AM0: 1367 W m^{-2}), and near Saturn, the irradiance drops even further to ≈ 0.01 AM0, with temperatures dropping to ≈ 180 and 100 K, respectively (Figure 1A). These low-

intensity, low-temperature (LILT) environments are prevalent in the outer reaches of our solar system, but solar cells in inner orbits may also need to operate under similar conditions during an eclipse or when illuminated solely by the albedo from the Earth or Moon. Solar-powered space missions targeting the LILT areas must be optimized not only to withstand harsh environments and extreme temperature fluctuations but also to maintain sufficient power conversion under very low irradiance. Recently reported self-healing properties and thermal cycling tolerance of single-junction PSCs form the foundation of highly sustained performance, underscoring the robustness of perovskites under LILT scenarios.^[28–32]

In this study, we investigated the performance of single-junction and tandem perovskite solar cells under varying temperatures and light intensities, to understand their performance under low-intensity light and low-temperature conditions. Cooling 2J-PSCs from 300 to 80 K under AM0, 0.1 AM0, and 0.01 AM0 illumination, we found that their power conversion efficiency (PCE) dropped by 89%_{rel} at very low temperatures. This drop in PCE with decreasing temperature was primarily due to a decreased fill factor (FF), while open-circuit voltage (V_{OC}) and short-circuit current (J_{SC}) exhibited only minor variations. In contrast, the 1.54 eV 1J-PSC maintained its initial PCE from 300 to

140 K. Combining temperature-dependent absolute photoluminescence (PL) and an in-depth investigation of the 1.80 eV perovskite subcells, used in the 2J-PSC tandem we find halide segregation of the high Br-ratio based perovskite at temperatures below 250 K to be the underlying reason, and note that PCE losses were reversible upon heating.

2. Results and Discussion

To investigate if all-perovskite tandem solar cells can work efficiently under varying temperatures and light intensities relevant to outer planetary space conditions, we first fabricated 2J- and 1.54 eV 1J-PSCs following the device structures depicted in Figure 1B. For the 2J-PSC, we utilized 1.80 eV wide-bandgap and 1.27 eV low-bandgap perovskites, which were connected by an indium oxide (InO_x) interconnect, following our recent work.^[33] Full fabrication details and procedures are described in the [Experimental Section](#). As-fabricated 2J-PSCs reached efficiencies of 23.7% under AM1.5G illumination, as shown in the statistical distributions in Figure S22 (Supporting Information). The 1J-PSC structure consisted of a $\text{Cs}_{0.05}\text{FA}_{0.95}\text{PbI}_3$ single-halide perovskite layer, with an efficiency of 21% under AM1.5G illumination.^[34]

Under AM0 illumination and at room temperature, both devices performed well with AM0 efficiencies of 20% (2J-PSC) and 18% (1.54 eV 1J-PSC), as shown in Table S1 (Supporting Information). However, at lower temperatures ranging from 300 K down to 80 K and three different light intensities: AM0, 0.1 AM0, and 0.01 AM0, we observe striking differences as shown in Figure 1C and Figures S1–S3 (Supporting Information). The 2J-PSC experienced a rapid PCE loss until 200 K across all illumination intensities. As the temperature further decreased toward 80 K, the PCE performance continued to decrease, albeit slower, declining to $\approx 89.3\%_{\text{rel}}$ and $82.6\%_{\text{rel}}$ for AM0 and 0.1 AM0 illumination, respectively. Only under 0.01 AM0 illumination, did the PCE begin to stabilize at $\approx 51.6\%_{\text{rel}}$ of the initial efficiency.

In complete contrast to 2J-PSC, the 1.54 eV 1J-PSC exhibited increased performance under AM0 and 0.1 AM0 irradiation as the temperature decreased. It then maintained its PCE without significant loss down to 150 K, followed only by a $30\%_{\text{rel}}$ decrease as the temperature dropped further to 80 K. Under 0.01 AM0 illumination, it exhibited an almost linear PCE trend, with a slight increase in the beginning and consistently remaining above the room temperature (RT) value, even at very low temperatures. To provide further insights into these differences in performance and working mechanisms we then simulated realistic conditions: Scenario 1: AM0 300 K (Earth's Orbit-like conditions), Scenario 2: 0.1 AM0 180 K (Asteroid Belt-like conditions), Scenario 3: 0.01 AM0 100 K (Jupiter-like conditions), and compare the current density-voltage (J - V) curves of the 1.54 eV 1J-PSC and 2J-PSC against each other in Figure 1D–F. Further temperature-dependent J - V curves in the range from 300 to 80 K for AM0, 0.1 AM0, and 0.01 AM0 are presented in Figures S1–S3 and S15–S17 (Supporting Information), respectively. Notably, the 1.54 eV 1J-PSC exhibits J - V characteristics without an S-shape or hysteresis at a scan speed of 154 mV s^{-1} in all scenarios, with a PCE of $\approx 18\%$ (Earth Orbit-like, AM0, 300 K), a PCE $> 18\%$ for Asteroid Belt-like environments (0.1 AM0, 180 K), and a PCE of $\approx 13\%$ for Jupiter-like environments (0.01 AM0, 100 K). In con-

trast, the 2J-PSC develops a pronounced S-shape at Asteroid Belt- and Jupiter-like conditions, limiting the PCE to 10% and 9%, respectively. In addition to the temperature-dependent PCE trends shown in Figure 1C, a reversible valley in PCE is observed near 180 K in both the 2J-PSC and 1.54 eV 1J-PSC under different light intensities, which could stem from low-temperature metastable states previously observed by Barone et al.^[35] In summary, the 1.54 eV 1J-PSC exhibits stable and efficient performance across all test conditions. On the other hand, the 2J-PSC suffers from significant performance losses and further pronounced S-shape-like J - V characteristics under LILT conditions. These findings highlight the superior efficiency and stability of the 1.54 eV 1J-PSCs over 2J-PSCs in low-temperature and low-intensity environments.

To disentangle the underlying causes of the performance difference, we quantified the quasi-Fermi level splitting (QFLS) as a function of light intensity (Suns) for separate 1.27, 1.54 and 1.80 eV 1J-PSCs, at different temperatures (300, 200, and 100 K) by means of absolute photoluminescence quantum yield (PLQY) measurements (See [Supporting Information](#) for measurement, calculation, and fabrication details). As an all-optical measurement, this allows us to understand the limitations imposed by non-radiative recombination without transport limitations present. Figure 2A displays the QFLS results for 1.80, 1.54, and 1.27 eV 1J-PSCs at $T = 300, 200,$ and 100 K . Notably, for the 1.80 and 1.27 eV compositions used in the 2J-PSC, we observe negligible differences in ideality and QFLS. To understand to what extent this impacts device performance, we derived pseudo- J - V (pJ - V) curves that allow quantifying the maximal PCE potential in the absence of extraction and/or series resistance losses. The equations and steps used to derive QFLS from intensity-dependent photoluminescence measurements and to construct pseudo- J - V curves are also detailed in the [Supporting Information](#). Pseudo- J - V curves of the 2J-PSC, constructed from the 1.80 and 1.27 eV QFLS versus light-intensity data, reveal well-behaved J - V characteristics with high pseudo-FF and high pseudo-PCE values. Comparing these pJ - V curves with measured J - V characteristics reveals noticeable differences for low temperatures, where the J - V measurement exhibits significant S-shape-like behavior. In comparison, pJ - V curves of the 1.54 eV 1J-PSC, Figure 2B, are well-aligned with measured J - V curves across all temperatures examined. This corroborates that the 1.54 eV 1J-PSC maintains high efficiency over the entire temperature range and experiences minimal resistive and recombination losses at very low temperatures.

This discrepancy between J - V and pJ - V curves aligns with the well-known temperature response of perovskite solar cells, in which FF drops sharply upon cooling while V_{OC} changes only slightly and J_{SC} remains largely stable. Pseudo- J - V curves confirm that light absorption and intrinsic recombination are stable across the investigated temperature range, reinforcing that the bottleneck lies in carrier extraction rather than in the perovskite absorbers themselves. Cooling reduces the conductivity of charge-transport layers and increases interfacial charge-transfer resistance, causing a sharp rise in series resistance and the emergence of S-shaped J - V curves.^[30,36–39]

To explore whether phase transitions and bandgap variations at lower temperatures contribute to extraction or injection issues in the devices, we further investigated the temperature-dependent

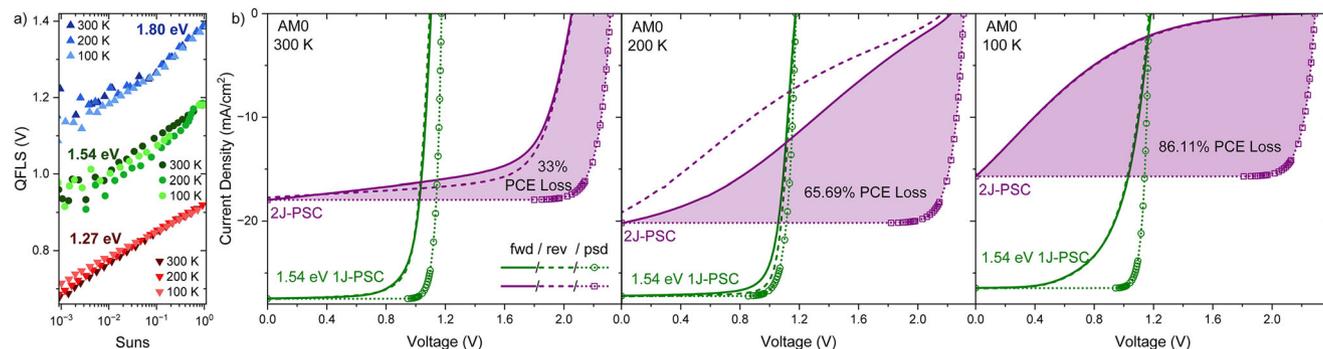


Figure 2. Temperature-Dependent Quasi-Fermi Level Splitting (QFLS) and J - V Characteristics of 1J- and 2J-PSCs. a) QFLS as a function of illumination intensity (Suns) for 1.8 eV (blue), 1.54 eV (green), and 1.27 eV (red) 1J-PSCs, extracted from intensity-dependent PL measurements at temperatures of 300, 200, and 100 K. b) Comparison of measured J - V (solid lines) and pseudo- J - V (dotted lines with markers) characteristics of 1J- and 2J-PSCs under AMO illumination at 300, 200, and 100 K (p - J - V curves of the 2J-PSC were constructed from individual QFLS-suns curves of 1.27 and 1.80 eV 1J-PSCs).

photoluminescence spectra of the 1.27, 1.54, and 1.80 eV 1J-PSCs. **Figure 3A–C** presents temperature-dependent PL intensity maps together with the maximum peak positions. We find the 1.54 eV 1J-PSC to be largely temperature-insensitive, with only a slight redshift of 10 meV in the PL peak position as the temperature decreases from 300 to 80 K (Figure 3B). In contrast, we observe notable changes for the 1.27 and 1.80 eV compositions. The PL peak position of the 1.27 eV 1J-PSC shifts from 1.22 to

1.15 eV as the temperature decreases from 300 K to 80 K, corresponding to a redshift of 70 meV. This is 7 times larger than the shift in the case of the 1.54 eV composition and may contribute to the observed PCE reductions in the tandem. The 1.80 eV 1J-PSC composition, on the other hand, exhibits a distinct spectral behavior. As shown in Figure 3C, we do not observe significant peak shifts of the main high-energy (HE) PL peak. Notably, we observe a second PL peak, representing low-energy (LE) states,

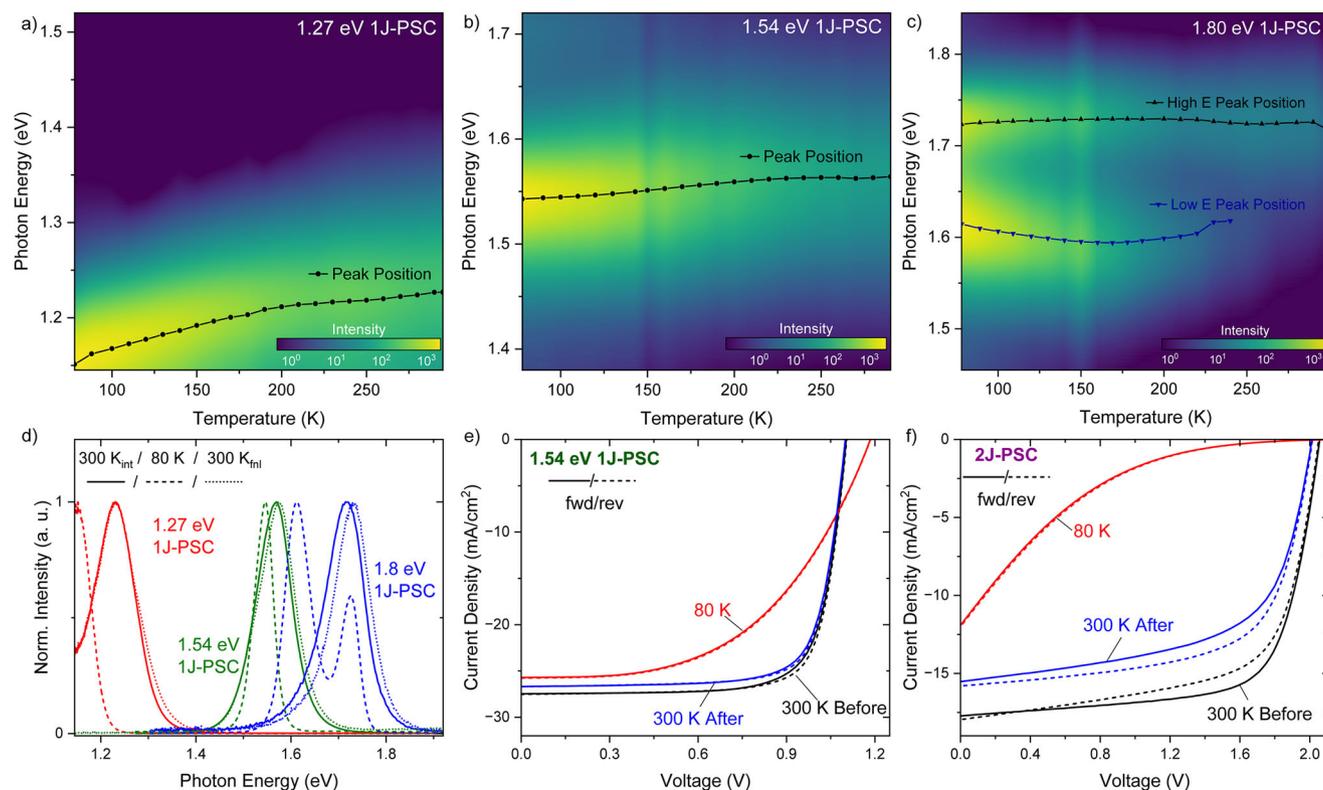


Figure 3. Temperature-dependent PL and J - V characteristics of 1J- and 2J-PSCs under AMO intensity. a–c) Temperature-dependent PL maps for 1.27 eV (a), 1.54 eV (b), and 1.80 eV (c) 1J-PSCs as a function of photon energy and temperature, with peak positions indicated. d) Normalized PL spectra of 1.27, 1.54, and 1.80 eV 1J-PSCs measured before cooling down (at 300 K), at 80 K, and after returning to room temperature. e, f) J - V curves of 1.54 eV 1J-PSC and 2J-PSC before cooling down (at 300 K), at 80 K, and after returning to room temperature (300 K), illustrating temperature-dependent changes and the reversible temperature-dependent properties of perovskite solar cells.

≈1.6 eV emerging at 240 K, and growing in intensity at lower temperatures.

Considering the high bromide-to-iodide ratio (60:40%) of the 1.80 eV 1J-PSC, we believe this lower-energy peak originates from halide segregation. Halide segregation is a well-known phenomenon in mixed perovskite compositions, where the mixed perovskite phase separates into Br-rich and I-rich phases. At room temperature, this can occur under prolonged photoexcitation, driving separation into Br- and I-rich domains against entropic remixing.^[40,41,42,43,44] Charge carriers then funnel into the low-bandgap iodide-rich domains, and therefore, PL is extremely sensitive to even the smallest fractions of iodide-rich domains.^[40,45–52] Our data in Figure 3C suggests that halide segregation is accelerated at temperatures below 240K, which we further discuss later on. Next, we examined whether the observed PL shifts were reversible upon heating the samples back to 300 K. Figure 3D–F displays corresponding PL spectra and J - V characteristics recorded at 300 K_{init} (solid line), 80 K (dashed line), and 300 K_{final} (dotted line). At 80 K, the PL peak of 1.27 eV 1J-PSC undergoes a noticeable redshift, while the 1.54 eV perovskite shows almost no change in peak energy. This difference originates from distinct lattice distortion mechanisms and lattice stiffness of the two materials. At room temperature, the Pb-Sn perovskite exhibits pronounced dynamic lattice distortions, which bend the I–Pb–I bonds and break the local symmetry. This weakens the Pb–I orbital coupling and widens its bandgap. As the temperature decreases, these dynamic distortions are suppressed, narrowing the bandgap and causing the observed redshift. The stiffer Pb-only lattice shows negligible distortion change, resulting in a slight shift in the PL.^[53] For all perovskite compositions, we observe a complete recovery of the peak energy to either its initial position or even slightly higher values. Most importantly, the halide-segregated low-energy states that appeared in the 1.80 eV perovskite at low temperatures also recovered completely. Consistent with this recovery in PL, measured J - V curves exhibit good recovery upon heating back to 300 K. Both V_{OC} and the overall curve shape of the 1J-PSC recover completely, but the J_{SC} experiences a slight reduction. Considering the complete recovery of the PL peak, this slight reduction is likely attributable to the undesired modifications within the charge transport layers. This effect becomes more pronounced in the 2J-PSC, which recovers with a more noticeable reduction of both J_{SC} and V_{OC} .

To understand if there is a connection between the low-temperature halide segregation starting at 240 K, and the deterioration of J - V characteristics with strong S-shape-like characters at low temperatures, see Figure 4A–D, we took a closer look at J - V measurements performed in forward and reverse directions. We observe increased hysteresis for 1.80 eV 1J-PSCs, which is also present in 2J-PSCs containing a 1.80 eV subcell. We therefore believe that the number of mobile ions is significantly increased upon halide segregation, causing the increased hysteresis. Interestingly, when comparing the measured V_{OC} versus QFLS of the 1.80 eV 1J-PSCs in Figure 4D, we observe an abrupt increase in the mismatch between the two, pointing to severe non-radiative recombination and low radiative efficiency of the mixed phase. This is supported by the almost-vanishing electroluminescence of the 1.80 eV subcell at ≈230 K (Figure S4, Supporting Information).

Looking at Figure 4C, we further notice an increase in J_{SC} of the 1.80 eV subcell at ≈230 K, which stems from halide segregation, and now existing low-bandgap phases. In essence, these extend the absorption range similar to a lowering of the apparent bandgap. Interestingly, the J_{SC} of the 2J-PSC follows this increase, despite using a monolithic interconnection. To understand if this can occur in real-life monolithically interconnected tandem solar cells with non-ideal shunt resistances, we performed LT-spice simulations using a series connection of two single-diode equivalent circuit models for the tandem. The input parameters for the model are shown in Table S2 (Supporting Information). The solid-line J - V curves in Figure 4E represent measurements from 300 to 190 K. The observed changes in the J - V characteristics in this region, such as the increase in J_{SC} and the appearance of an S-shape, closely match the simulated J_{SC} mismatch scenario in Figure 4F. This correspondence indicates that the performance of the 2J-PSC in this regime is primarily affected by halide segregation-induced current mismatch. As shown in Figure 4F, this J_{SC} imbalance can be well reproduced in the simulations, leading to the similar S-shape-like behavior observed experimentally in Figure 4E. Altogether, this strongly limits the performance of the 2J-PSC at low temperatures down to 200 K, while devices employing perovskite compositions with no Br content, such as the 1.54 eV 1J-PSCs are not affected. Having established this phenomenological connection between halide segregation and dropping device performance of 1.80 eV-based 1J- and 2J-PSCs at 250–200 K, the question of why halide segregation is accelerated at this temperature regime arises. To answer this, one needs to look at the thermodynamic origin of light-induced halide segregation as proposed by Chen et al.^[45] Their phase diagrams, also shown in Figure 5B, predict unstable mixtures for Br-to-I ratios between 0.2 and 0.5 at temperatures below 250 K. The 1.80 eV perovskite utilized in this study is based on a Br ratio of 0.4 and thus follows their prediction and demixes at temperatures below 250 K.

To isolate the temperature effect on photoinduced halide segregation, we performed a dark-cooling control experiment (Figure S23, Supporting Information). In this test, 1.80 eV 1J-PSCs were cooled to 80 and 180 K in the dark, and their PL spectra were recorded as a function of time. At 80 K, as expected, no segregation was observed since ion mobility is effectively frozen at this temperature. At 180 K, on the other hand, halide segregation is more pronounced and occurs more rapidly than at room temperature. This behavior results from the temperature-dependent interplay between ionic mobility and the thermodynamic factors in the Helmholtz free energy, a function of internal energy, temperature, and entropy: $F = U - TS$.^[54,55] At 180 K, ions remain sufficiently mobile for halide migration, but the entropic stabilization and photothermal remixing are strongly suppressed. Consequently, the enthalpic penalty from lattice mismatch dominates, driving rapid demixing. At room temperature, entropy- and photoheating-related processes become more pronounced and partially counteract segregation, slowing its kinetics.^[56,57]

Looking at Figure 4E as well as Figure 1C and Figures S5–S17 (Supporting Information), we find another decline in performance below 150 K at 1 and 0.1 AM0 light conditions, stemming predominantly from a reduction in FF and J_{SC} . This second decline is universal for the 2J-PSCs, as well as all 1J-PSCs, including the 1.80, the 1.54, and the 1.27 eV compositions. In all

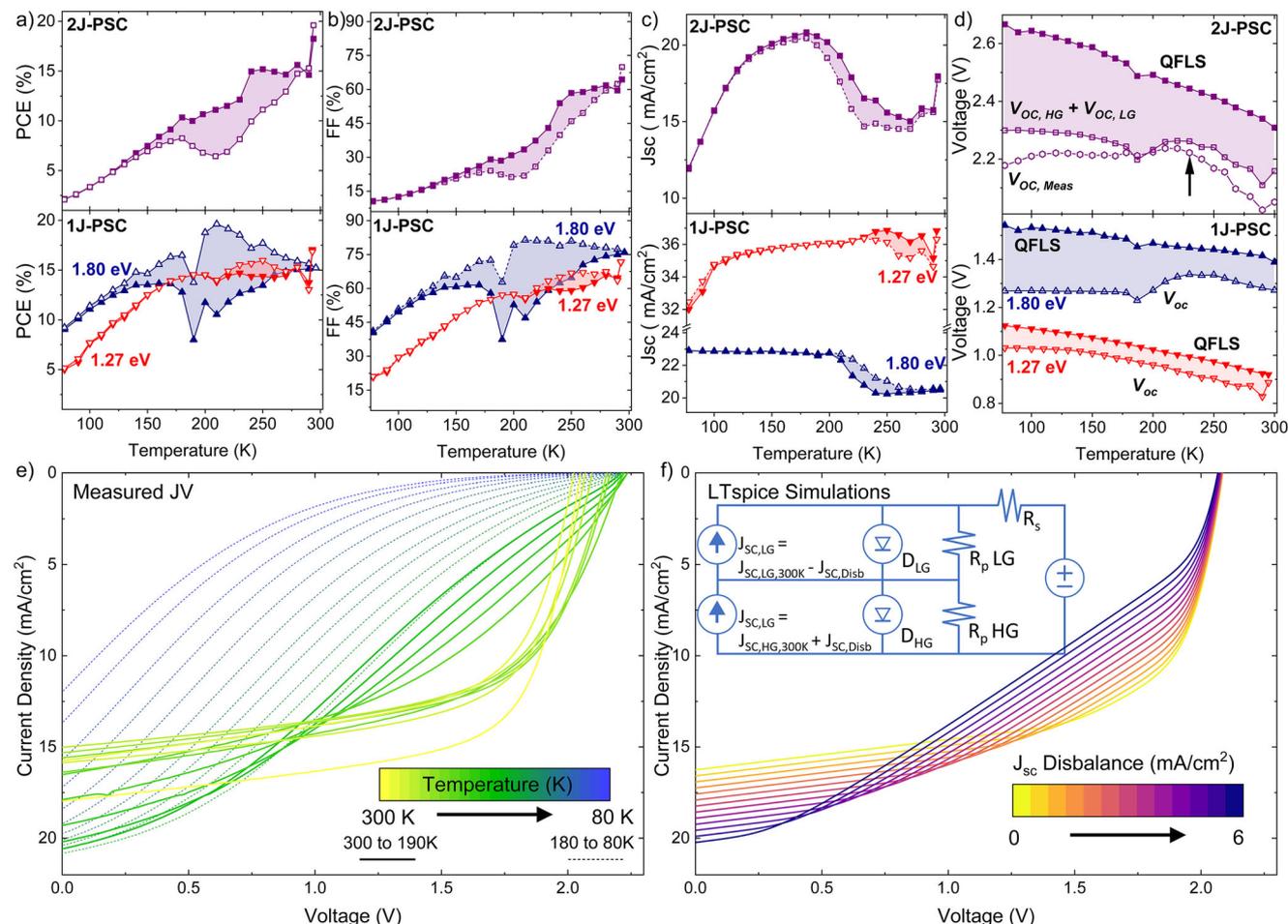


Figure 4. Temperature-dependent performance analysis of 2J-PSC under AM0 illumination. a–d) Calculated photovoltaic parameters, PCE, FF, J_{sc} , and QFLS/ V_{oc} , of the 2J-PSC (top) and the individual 1.80 eV (blue) and 1.27 eV (red) 1J-PSC subcells (bottom) across the temperature range of 300–80 K under AM0 illumination. The black arrow highlights 240 K, a key point. e) Temperature-dependent measured $J-V$ curves of the 2J-PSC under AM0 illumination, from 300 to 80 K with 10 K increments. $J-V$ curves of the halide segregation-affected and transport layer properties-affected regions are presented via solid and dashed lines, respectively. f) LTspice simulations of 2J-PSC with J_{sc} imbalance. The input parameters for the equivalent circuit models can be found in Table S2 (Supporting Information). Note that the LTspice simulations were focused on current disbalance and additional temperature effects arising, e.g., from impeded hopping transport in C_{60} is not considered here, but discussed later.

cases, our devices use C_{60} as an electron transport layer, which relies on the hopping transport of charge carriers and thus experiences a strong reduction in conductivity upon cooling.^[58] Notably, this starts to impact device performance only below ≈ 150 K, with the tandem device, utilizing two C_{60} transport layers, being influenced the most. Drift diffusion simulations of a 1.54 eV 1J-PSC (Figure S21, Supporting Information) confirm that increasing C_{60} thickness raises series resistance and reduces FF, while decreasing electron mobility by orders of magnitude, mimicking the cooling-induced drop in hopping transport, produces a much stronger FF loss, consistent with the compounded low-temperature degradation observed in 2J-PSCs.

3. Conclusion

In conclusion, we investigated the performance of all-perovskite tandem solar cells (2J-PSC) across a wide temperature range from 300 K to 80 K and under varying solar irradiance intensi-

ties, aiming to elucidate their potential beyond terrestrial applications. We find reliable operation in Earth Orbit-like conditions (1AU, AM0, 300 K), but for Asteroid Belt-like (0.1 AM0, 180 K) and Jupiter-Orbit-like (0.01 AM0, 100 K) conditions, we observe low performance due to S-shape-like $J-V$ characteristics for 2J-PSCs. 1.54 eV 1J-PSC investigated as a comparison maintains good performance. Pseudo- $J-V$ characteristics, constructed from PL measurements of the individual subcells suggest the high-performance potential of the 2J-PSCs, excluding trap-assisted recombination as a limiting factor. Investigating PL spectra, we identify halide segregation to abruptly increase at 230 K, coinciding with the abrupt deterioration of FF, V_{oc} , and PCE of the 2J-PSC and an increased hysteresis. The segregation further led to current density imbalances in the monolithic tandem, which then caused S-shape-like $J-V$ characteristics. Altogether, halide segregation and current density mismatch cause a strong decrease of 2J-PSCs performance at low temperatures. We therefore propose to utilize single-halide perovskite compositions that

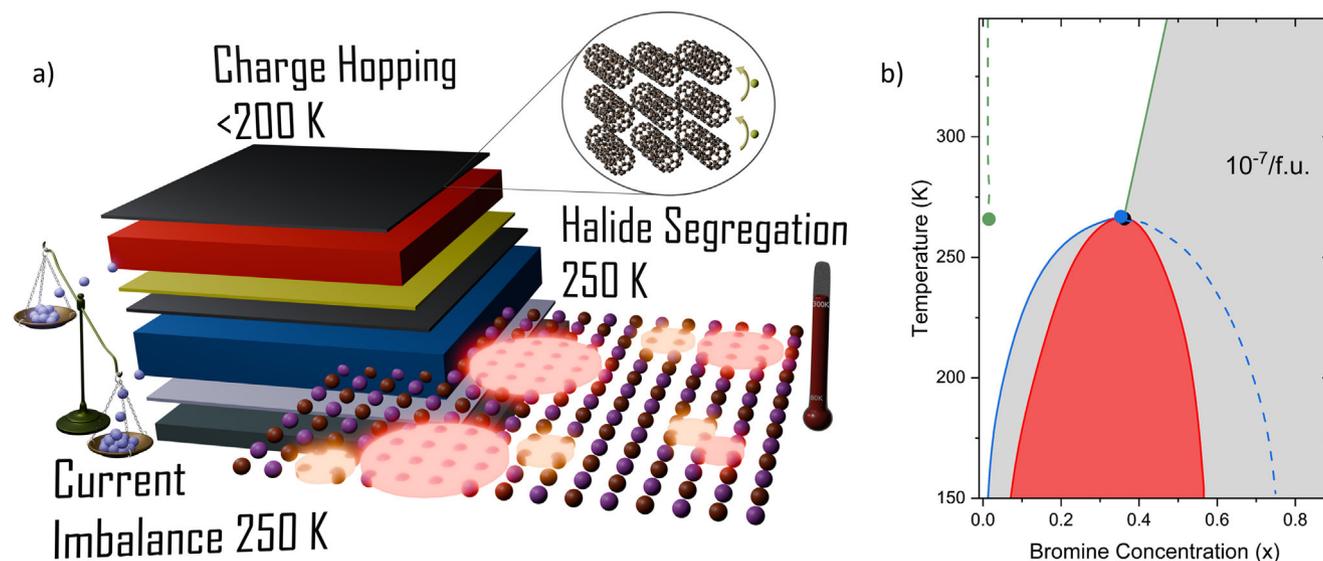


Figure 5. Schematic representation of different phenomena either affecting the performance of 2J-PSC or triggered by the temperature decrease. a) Illustration of halide segregation in the 1.80 eV perovskite subcell, charge hopping limitations in the electron transport layer (ETL), and current mismatch between the subcells of the 2J-PSC. b) phase diagram for photocarrier density $n = 10^{-7}$ per formula unit. (Corresponds to ≈ 1 Sun). Spinodal boundaries, shown as red lines, divide the metastable (gray) and unstable (pink) regions. Binodal boundaries, represented by solid blue and solid green lines, separate the stable (white) and metastable regions, with blue lines indicating compositional binodals and green lines showing light-induced binodals. Nucleation becomes favorable for a phase with Br concentration, indicated by dashed blue (green) lines when the metastable region is entered by crossing compositional (light-induced) binodals. The dots mark where three phases can coexist: the original parent phase (black dots) alongside two nucleated phases containing different Br concentrations (blue and green dots). Figure adapted and digitized from Zehua Chen et al. *Nat. Commun.* 2021, 12, 2375. 2021 The Authors. Licensed under CC BY.

are not subject to halide segregation and that, as well shown, perform reliably until the lowest temperatures for outer-space applications. All-perovskite tandem solar cells, nevertheless, could outperform perovskite-based single junctions in Earth-orbit-like conditions, where operation under low temperatures is not required.

4. Experimental Section

Materials: Methylammonium iodide (MAI, >99.99%), formamidine iodide (FAI, >99.99%), methylammonium bromide (MABr, 99.99%) were purchased from Greatcell. Cesium iodide (CsI, 99.9%), tin (II) iodide (SnI_2 , 99.99%), tin (II) fluoride (SnF_2 , 99%), guanidine thiocyanate (GuaSCN, >99%), and glycine hydrochloride (GlyHCl, 99%) were purchased from Sigma–Aldrich. Lead (II) iodide (PbI_2 , 99.99%) and lead (II) bromide (PbBr_2 , 98%) were obtained from TCI. Dimethylformamide (DMF, anhydrous, 99.8%) and dimethyl sulfoxide (DMSO, anhydrous, 99.9%) were used as solvents. Chlorobenzene (CB, anhydrous, 99.8%) and ethyl acetate (EA, anhydrous, 99.8%) were used as antisolvents. PTFE syringe filters (0.45 μm pore size) were used for precursor filtration. [2-(3,6-Dimethoxy-9H-carbazol-9-yl)ethyl]phosphonic acid (2PACz) was purchased from TCI and used as the hole-selective self-assembled monolayer (SAM). PEDOT:PSS (Heraeus Clevis AL3083) was used as the hole transport layer. Aluminum-doped zinc oxide (AZO) nanoparticle dispersion (N21X) was obtained from Avantama. Tetrakis(dimethylamino)tin(IV) (TDMA-Sn) and cyclopentadienylindium (CpIn) for ALD of SnO_x and InO_x were purchased from Strem Chemicals. Fullerene (C_{60} , 99.95%, M. Braun Intergas-Systeme GmbH), bathocuproine (BCP, 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline, 99%, Sigma–Aldrich), and copper pellets (99.99%, Kurt J. Lesker) were used for thermal evaporation. Lithium fluoride (LiF, Alfa Aesar) was used as an interfacial layer material.

Preparation of Pb-Sn Perovskite Solution: The perovskite solution was prepared using a recipe adapted from Hu et al.^[59] The mixed-metal solution with a total concentration of 1.80 M was prepared by dissolving MAI, FAI, CsI, SnI_2 , and PbI_2 in a mixture of DMF:DMSO (1:3, volume ratio). Relative to the amount of tin metal, 10 mol% SnF_2 , 2 mol% GuaSCN, and 2 mol% GlyHCl were added as additives. After complete dissolution of the precursors, metallic tin (Sn) powder was added to the precursor solution and stirred for 45 min at 40 °C. Metallic Sn powder was filtered out through a 0.45 μm PTFE filter immediately prior to perovskite deposition. All chemicals used for this solution were stored and weighed in a N_2 -filled glovebox to prevent contamination of the solution with O_2 or H_2O . Preparation of the solution was also carried out in a N_2 -filled glovebox.

Preparation of Single- and Mixed-Halide Perovskite Solutions: The solutions for the lead-based perovskites were prepared following a recipe adapted from Peña-Camargo et al.^[34] The 1.2 M FAPbI_3 solution, containing 10 mol% excess PbI_2 , was prepared by dissolving FAI and PbI_2 in a 4:1 (v/v) mixture of DMF:DMSO. The 1.2 M MAPbBr_3 solution, containing 10 mol% excess PbBr_2 , was prepared analogously by dissolving MABr and PbBr_2 in a 4:1 (v/v) mixture of DMF:DMSO. Both solutions were stirred overnight at room temperature. The so-called “MAFA” solutions were obtained with the desired I:Br ratio by mixing FAPbI_3 and MAPbBr_3 solutions in a volume ratio of x:y. Subsequently, 42 μL of a 1.5 M CsI solution in DMSO was added to 958 μL of each MAFA solution, resulting in nominal triple-cation stoichiometries of $\text{Cs}_{x,0.05}(\text{FA}_x\text{MA}_y)_{0.95}\text{Pb}(\text{I}_x\text{Br}_y)_3$. In this work, the composition with a 60:40 (I:Br) ratio corresponds to the mixed-halide perovskite with a nominal bandgap of 1.80 eV. When $x:y = 100:0$, the resulting double-cation single-halide composition $\text{Cs}_{0.05}\text{FA}_{0.95}\text{PbI}_3$ exhibits a nominal bandgap of 1.54 eV.

Device Fabrication: To remove any residual oils, dust, or contaminants that could lead to pinholes or shortcuts in the device structure, pre-patterned (2.5 \times 2.5 cm^2 , 15 Ω sq^{-1}) ITO substrates (Psiotec, UK) were sonicated subsequently in acetone, Hellmanex solution in deionized (DI) water, DI-water, acetone, and isopropanol, followed by drying under N_2 .

For Pb-Sn perovskite devices, substrates were treated with oxygen plasma (4 min, 120 W) and then transferred to a laminar-flow bench. Before deposition of the hole transport layer (HTL), PEDOT:PSS (poly(3,4-ethylenedioxythiophene):polystyrene sulfonate, Heraeus AL3083) was filtered through a 0.45 μm GMF filter. The HTL was spin-coated in a two-step program: 10 s at 500 rpm followed by 30 s at 4000 rpm, and then annealed at 120 °C for 10 min. The substrates were immediately transferred into the N_2 -filled glovebox and annealed at 120 °C for another 10 min. Perovskite films were spin-coated onto the HTL layer by depositing 120 μL of precursor solution on each sample. The spin-coating program was set to 1000 rpm for 10 s with a ramp of 200 rpm s^{-1} , followed by 4000 rpm for 40 s with an acceleration of 1000 rpm s^{-1} . During the last 20 s of spinning, 300 μL of CB was dropped at a constant flow onto the center of the substrate as the antisolvent. The films were then annealed in two steps: 10 min at 100 °C followed by another 10 min at 65 °C. The samples were then transferred directly into the evaporation chamber without breaking the inert atmosphere. C_{60} (30 nm)/BCP (8 nm)/Cu (100 nm) were sequentially deposited under vacuum ($p = 10^{-7}$ mbar). The overlap of the copper and the ITO electrodes defined the active area of the pixel (0.06 cm^2).

For single- and mixed-halide perovskite devices, substrates were directly transferred to the N_2 -filled glovebox following the UV-Ozone treatment (30 min). The hole-selective self-assembled monolayer (SAM) was prepared using 2PACz (1 mg mL^{-1} in ethanol) and spin-coated onto the ITO substrates at 3000 rpm for 30 s with an acceleration of 500 rpm s^{-1} . The substrates were subsequently annealed at 100 °C for 10 min before perovskite deposition. Both $\text{Cs}_{0.05}\text{FA}_{0.95}\text{PbI}_3$ and $\text{Cs}_{0.05}(\text{FA}_{60}\text{MA}_{40})_{0.95}\text{Pb}(\text{I}_{60}\text{Br}_{40})_3$ perovskite films were prepared by spin-coating 120 μL of perovskite solution at 4000 rpm for 40 s with 1334 rpm s^{-1} acceleration. At the 10th second, 300 μL of ethyl acetate was dropped at a constant flow onto the center of the spinning substrates as the antisolvent. The films were then annealed for 1 h at 100 °C. The samples were loaded into the evaporation chamber. For optimized 1.80 eV 1J-PSCs, 0.8 nm of LiF was deposited prior to C_{60} followed by sequential deposition of C_{60} (30 nm), BCP (8 nm), and Cu (100 nm) under high vacuum ($p = 10^{-7}$ mbar).

For all perovskite 2J-PSCs, the high-bandgap, mixed-halide perovskite solar cells were prepared as described above up to the deposition of the C_{60} layer. Thereafter, an aluminium zinc oxide (AZO) nanoparticle dispersion (N21X, Avantama) was diluted 1:2 with isopropanol and spin-coated at 4000 rpm for 20 s with a 6 s ramp, followed by annealing at 80 °C for 90 min. The samples were then transferred into the Beneq TFS-200 ALD system. SnO_x and InO_x layers were sequentially grown from tetrakis(dimethylamino)tin(IV) (TDMA-Sn, Strem) + H_2O and Cyclopentadienylindium (CpIn, Strem), O_2 (99.999%) + H_2O , respectively. TDMA-Sn and CpIn were maintained in heated sources at 45 °C and 50 °C, respectively, while H_2O was kept in a liquid source at room temperature. The reactor temperature during both deposition processes was set to 80 °C. After the deposition of the interconnect, the tandems were finished in the same manner as described above for the low-gap perovskite single junctions, by deposition of PEDOT:PSS, low-bandgap perovskite, C_{60} , BCP, and Cu.

Device Characterization: To perform temperature-dependent measurements, samples were loaded into a cryostat in the N_2 -filled glovebox. Afterward, the system was evacuated and kept under continuous vacuum during the measurements. The temperature control was maintained via a PID controller connected to a liquid nitrogen supply. Intensity-dependent measurements were performed using an LED light source. The light intensity was adjusted to have the J_{SC} correspond to the desired irradiance intensity, calculated relative to $J_{\text{SC,AM1.5G}}$. Current density–voltage (J – V) characterizations of solar cells were performed using a Keithley 2400 source-measure unit (SMU) with a scan rate of 154 mV s^{-1} , at 136 mW cm^{-2} (AM0), 13.6 mW cm^{-2} (0.1 AM0), and 1.36 mW cm^{-2} (0.01 AM0) illumination. Absolute photoluminescence (PL) measurements at room temperature were performed using a 520 nm continuous-wave (CW) laser (Insware). The intensity of the laser was calibrated to simulate the AM0 irradiance intensity of $\approx 136 \text{ mW cm}^{-2}$. An integrating sphere was used to collect the emitted light, which was directed to the Andor SR393iB spectrometer equipped with a silicon (DU420A-BR-DD, iDus) CCD via optical fiber cable. The system was calibrated by using a halogen lamp with spec-

ified spectral irradiance. A spectral correction factor for the CCD was established using a calibrated reference lamp. This correction aligned the detector's response with the correct spectral profile of the sample emission. The corrected spectral irradiance was then converted to spectral photon density by dividing each measurement by the photon energy ($h\nu$) at each wavelength, providing photon-based data suitable for photoluminescence analysis. Finally, the total photon counts for both excitation and emission spectra were calculated through numerical integration across their respective spectral ranges using MATLAB.^[60] Temperature-dependent relative PL measurements were performed using the same setup described above, except without the integrating sphere. The sample was placed into the cryostat, and the emitted light was guided directly to the CCD. The relative PL spectra were normalized relative to the absolute PL data. For intensity-dependent PL measurements, a continuously variable neutral density filter (ThorLabs) was used to tune the excitation irradiance. The light intensity was monitored simultaneously with a Si photodetector. The number of averages and detector exposure time were set to 30 and 30 μs , respectively. To avoid the unintended illumination during the rotation, an automated shutter was used to block the optical path. The procedure was controlled using an in-house NI LabVIEW code. QFLS and pseudo- J – V curves were extracted from PLQY data following established procedures (Supporting Information). The temperature-dependent electroluminescence (EL) measurements were performed using the same setup described for temperature-dependent PL measurements. A forward bias sufficient to inject a current equal to the J_{SC} was applied using a Keithley 2400 SMU.

Statistical Analysis: For the temperature-dependent PCE data shown in Figure 1C, values were normalized to the corresponding room-temperature PCE for each device. For the PL spectra shown in Figure 3D, each spectrum was normalized to its maximum intensity for better comparison of peak shifts and spectral evolution. Statistical distribution of device performance is presented in Figure S22 (Supporting Information), showing the PCE statistics of 18 2J-PSC devices as fabricated. The mean was indicated by the circle, and the shaded box represents the standard error of the mean (SEM). All data analyses were performed using OriginPro and Python.

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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Conflict of Interest

The authors declare no conflict of interest.

Data Availability Statement

The data that support the findings of this study are available from the corresponding author upon reasonable request.

Keywords

all-perovskite tandem solar cells, halide segregation, low-intensity and low-temperature conditions, narrow-bandgap perovskite, space photovoltaics, temperature-dependent performance, wide-bandgap perovskite

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